

### **Features**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Lead Free By Design/RoHS Compliant (Note 1)
- ESD Protected Up To 3KV
- "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability



**DMG1013UW** 

P-CHANNEL ENHANCEMENT MODE MOSFET

#### **Mechanical Data**

- Case: SOT-323 •
- Case Material: Molded Plastic, "Green" Molding Compound. • UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin annealed over Alloy 42 leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 2
- Ordering Information: See Page 2
- Weight: 0.006 grams (approximate)

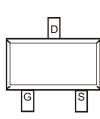


Top View



Drain

Equivalent Circuit



Top View

## **Maximum Ratings** $@T_A = 25^{\circ}C$ unless otherwise specified

Char	acteristic		Symbol	Value	Unit
Drain-Source Voltage			V <sub>DSS</sub>	-20	V
Gate-Source Voltage			V <sub>GSS</sub>	±6	V
Continuous Drain Current (Note 3)	Steady State	T <sub>A</sub> = 25°C T <sub>A</sub> = 85°C	ID	-0.82 -0.54	А
Pulsed Drain Current (Note 4)	I <sub>DM</sub>	-6	A		

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3)	PD	0.31	W
Thermal Resistance, Junction to Ambient $@T_A = 25^{\circ}C$ (Note 3)	R <sub>θJA</sub>	398	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	С°

1. No purposefully added lead. Notes:

Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.
Device mounted on FR-4 PCB, with minimum recommended pad layout.

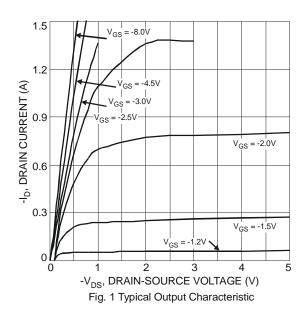
4. Repetitive rating, pulse width limited by junction temperature.

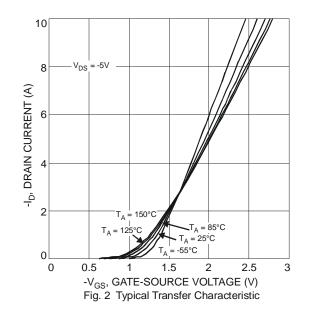


# Electrical Characteristics @T<sub>A</sub> = 25°C unless otherwise specified

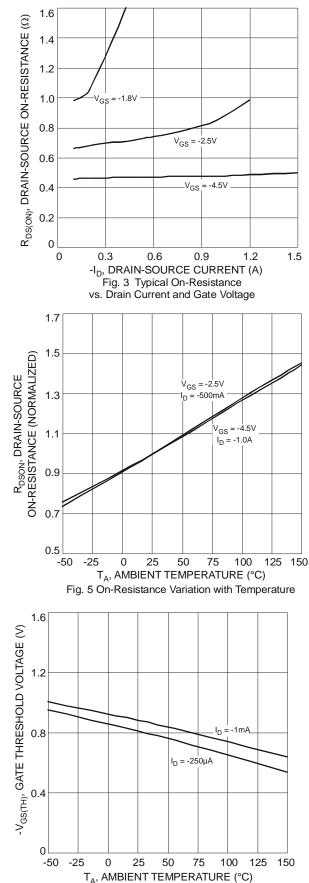
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 5)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	-	-	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current T <sub>J</sub> = 25°C	I <sub>DSS</sub>	-	-	-100	nA	$V_{DS} = -20V, V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>	-	-	±2.0	μA	$V_{GS} = \pm 4.5 V, V_{DS} = 0 V$
ON CHARACTERISTICS (Note 5)						
Gate Threshold Voltage	V <sub>GS(th)</sub>	-0.5	-	-1.0	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$
		-	0.5	0.75 1.05	Ω	$V_{GS} = -4.5V, I_D = -430mA$
Static Drain-Source On-Resistance	R <sub>DS (ON)</sub>		0.7			$V_{GS} = -2.5V, I_D = -300mA$
			1.0	1.5		$V_{GS} = -1.8V, I_D = -150mA$
Forward Transfer Admittance	Y <sub>fs</sub>	-	0.9	-	s	$V_{DS} = -10V, I_D = -250mA$
Diode Forward Voltage	V <sub>SD</sub>		-0.8	-1.2	V	$V_{GS} = 0V, I_{S} = -150mA$
DYNAMIC CHARACTERISTICS (Note 6)						
Input Capacitance	Ciss	-	59.76	-	pF	
Output Capacitance	C <sub>oss</sub>	-	12.07	-	pF	$V_{DS} = -16V, V_{GS} = 0V,$ - f = 1.0MHz
Reverse Transfer Capacitance	C <sub>rss</sub>	-	6.36	-	pF	
Total Gate Charge	Qg	-	622.4	-	рС	
Gate-Source Charge	Q <sub>gs</sub>	-	100.3	-	рС	V <sub>GS</sub> = -4.5V, V <sub>DS</sub> = -10V, I <sub>D</sub> = -250mA
Gate-Drain Charge	Q <sub>gd</sub>	-	132.2	-	рС	$I_D = -23011A$
Turn-On Delay Time	t <sub>D(on)</sub>	-	5.1	-	ns	
Turn-On Rise Time	tr	-	8.1	-	ns	$V_{DD} = -10V, V_{GS} = -4.5V,$
Turn-Off Delay Time	t <sub>D(off)</sub>	-	28.4	-	ns	$R_L = 47\Omega, R_G = 10\Omega,$ $I_D = -200 \text{mA}$
Turn-Off Fall Time	t <sub>f</sub>	-	20.7	-	ns	-20011A

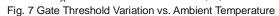
 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing. Notes:

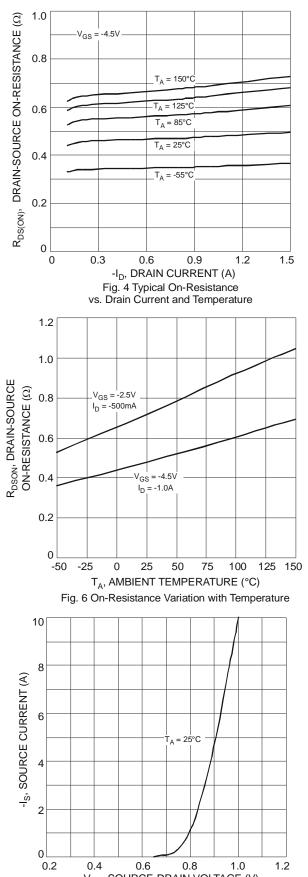










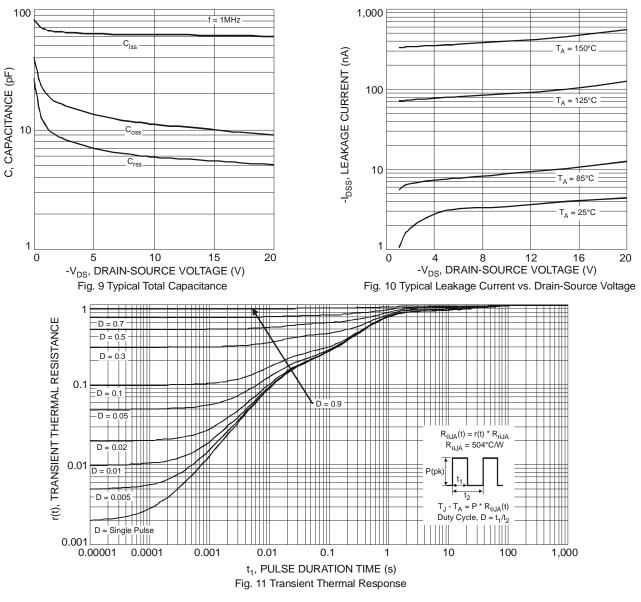


-V<sub>SD</sub>, SOURCE-DRAIN VOLTAGE (V) Fig. 8 Diode Forward Voltage vs. Current

DMG1013UW Document number: DS31861 Rev. 3 - 2



# **DMG1013UW**

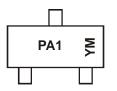


### Ordering Information (Note 7)

Part Number	Case	Packaging
DMG1013UW-7	SOT-323	3000 / Tape & Reel

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**



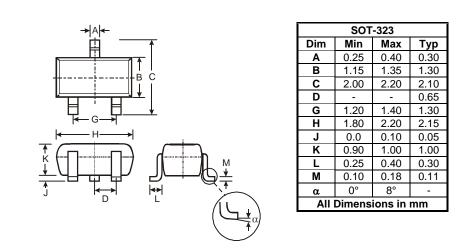
PA1 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: W = 2009) M = Month (ex: 9 = September)

Date	Code	Key

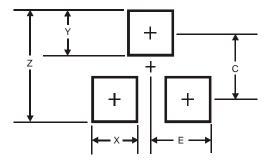
Year	2008	2	009	2010	2	2011	2012		2013	2014		2015
Code	V		W	Х		Y	Z		А	В		С
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



# **Package Outline Dimensions**



# Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.8
Х	0.7
Y	0.9
С	1.9
E	1.0



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